

DOCKET NO: 247866US2S



IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :  
AKIRA HOKAZONO, ET AL. : EXAMINER: MAGEE, T.  
SERIAL NO: 10/759,205 :  
RCE FILED: HERewith : GROUP ART UNIT: 2811  
FOR: SEMICONDUCTOR DEVICE :  
HAVING METAL SILICIDE FILMS  
FORMED ON SOURCE AND DRAIN  
REGIONS AND METHOD FOR  
MANUFACTURING THE SAME

AMENDMENT FILED CONCURRENTLY WITH REQUEST FOR CONTINUED  
EXAMINATION UNDER 37 C.F.R. § 1.114

COMMISSIONER FOR PATENTS  
ALEXANDRIA, VIRGINIA 22313

SIR:

In response to the Office Action dated June 29, 2005, please amend the above-identified application as follows:

**Amendments to the Claims** are reflected in the listing of claims which begins on page 2 of this paper.

**Remarks/Arguments** begin on page 7 of this paper.